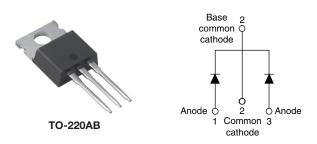
Vishay Semiconductors

# www.vishay.com





PRODUCT SUMMARY								
I <sub>F(AV)</sub>	2 x 15 A							
V <sub>R</sub>	35 V, 40 V, 45 V							
V <sub>F</sub> at I <sub>F</sub>	0.56 V							
I <sub>RM</sub> max.	15 mA at 125 °C							
T <sub>J</sub> max.	175 °C							
E <sub>AS</sub>	27 mJ							
Package	TO-220AC							
Diode variation	Common cathode							

### FEATURES

- 175 °C T<sub>J</sub> operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-30CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	30	A						
V <sub>RRM</sub>	Range	35 to 45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	А						
V <sub>F</sub>	20 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.56	V						
TJ	Range	-55 to 175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-30CTQ035HN3	VS-30CTQ040HN3	VS-30CTQ045HN3	UNITS				
Maximum DC reverse voltage	V <sub>R</sub>	35	40	45	V				
Maximum working peak reverse voltage	V <sub>RWM</sub>		40	45	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 127 °C,	30						
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1060	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	256					
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 3.0 \ A, \ L = 4.40 \ r$	20	mJ					
Repetitive avalanche current	I <sub>AR</sub>		Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>B</sub> typical						

Revision: 05-Mar-14 1 Document Number: 94959 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



## Vishay Semiconductors

ELECTRICAL SPECIFICATIONS
---------------------------

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
		15 A	T <sub>.1</sub> = 25 °C	0.62	v				
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.76					
	VFM ()	15 A	T _ 125 °C	0.56					
		30 A	T <sub>J</sub> = 125 °C	0.70					
Maximum reverse leakage curent	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2	mA				
See fig. 2	IRM ("	T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	15					
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal rar	900	pF					
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs				

#### Note

Г

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANIC	CAL SPECIFI	CATIONS			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 175	°C	
Maximum thermal resistance,	R <sub>thJC</sub>	DC operation See fig. 4	3.25		
junction to case per leg	<b>h</b> thJC	DC operation	°C/W		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approximate weight			2.0	g	
Approximate weight			0.07	oz.	
minimu	m		6 (5)	kgf ⋅ cm	
Mounting torque maximu	ım		12 (10)	(lbf ⋅ in)	
			30CT0	Q035H	
Marking device		Case style TO-220AB	30CT0	Q040H	
			30CT0	Q045H	



**Vishay Semiconductors** 

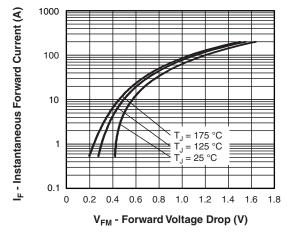


Fig. 1 - Maximum Forward Voltage Drop Characteristics

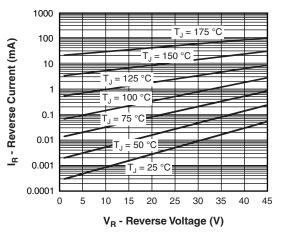


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

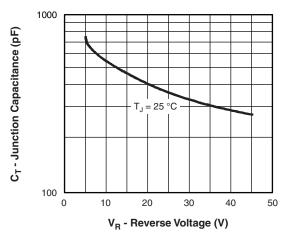


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

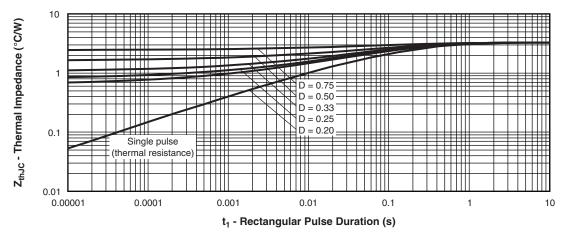


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

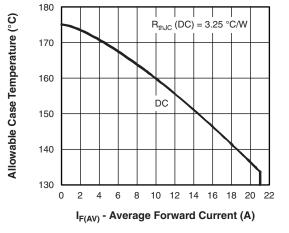
 Revision: 05-Mar-14
 3
 Document Number: 94959

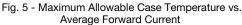
 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

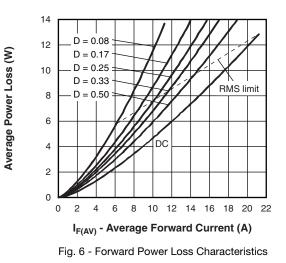


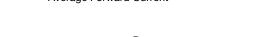
### VS-30CTQ0..HN3 Series

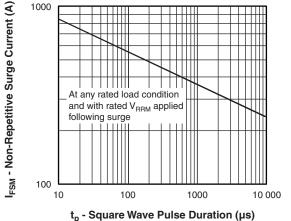
**Vishay Semiconductors** 













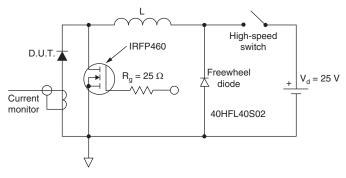


Fig. 8 - Unclamped Inductive Test Circuit

# VS-30CTQ0..HN3 Series



### **ORDERING INFORMATION TABLE**

Device code	VS-	30	С	т	Q	045	н	N3
				<u> </u>				
		2	3	4	5	6	$\overline{7}$	8
	_							
	1	- Visl	nay Sen	niconduo	ctors pro	oduct		
	2 -	Cur	rent rati	ng (30 =	30 A)			
	3 -	Circ	uit conf	iguratior	1:			
		C =	Commo	on catho	de			
	4 -	Pac	kage:					
		Т =	TO-220	)				
	5 -	Sch	ottky "Q	" series			035 = 3	35 V
	6 -	- Volt	age rati	nas —			040 = 4	
	7		0	101 qua	lified		045 = 4	45 V
				•	meu			,
	8 -			ntal digit				
		• N	3 = Hal	ogen-fre	e, RoHS	S comp	iant, an	d totally

ORDERING INFO	RMATION (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-30CTQ035HN3	50	1000	Antistatic plastic tube
VS-30CTQ040HN3	50	1000	Antistatic plastic tube
VS-30CTQ045HN3	50	1000	Antistatic plastic tube

	LINKS TO RELAT	ED DOCUMENTS						
Dimensions www.vishay.com/doc?95222								
Part marking information	TO-220AB-N3	www.vishay.com/doc?95028						



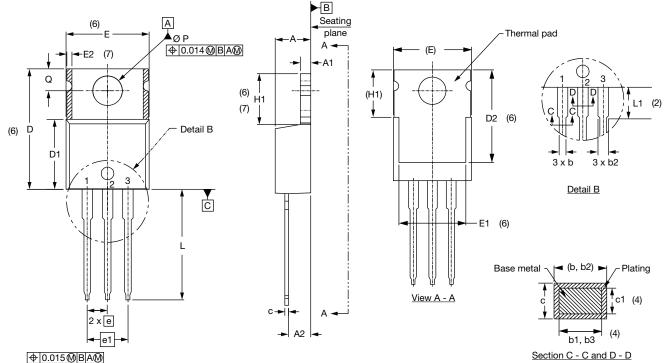
## **Outline Dimensions**



**Vishay Semiconductors** 

**TO-220AB** 

#### **DIMENSIONS** in millimeters and inches



Lead tip

Conforms to JEDEC<sup>®</sup> outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES		NOTES	NOTES		HES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES						
А	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6					
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6					
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6					
b	0.69	1.01	0.027	0.040			E2	-	0.76	-	0.030	7					
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105						
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208						
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7					
с	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552						
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2					
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147						
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118						

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimensions: inches

<sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1

<sup>(7)</sup> Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC<sup>®</sup> TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Revision: 06-Mar-2020 1 Document Number: 95222 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.